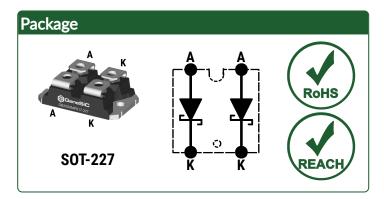
# GeneSiC SEMICONDUCTOR

### Silicon Carbide Schottky Diode

 $V_{RRM}$  = 1700 V  $I_{F(T_{C} = 100^{\circ}C)}$  = 182 A \*  $Q_{C}$  = 1076 nC \*

#### **Features**

- Low V<sub>F</sub> for High Temperature Operation
- Enhanced Surge and Avalanche Robustness
- Superior Figure of Merit Q<sub>C</sub>/I<sub>F</sub>
- Low Thermal Resistance
- Low Reverse Leakage Current
- Temperature Independent Fast Switching
- Positive Temperature Coefficient of V<sub>F</sub>
- Low V<sub>F</sub> for High Temperature Operation



#### **Advantages**

- Improved System Efficiency
- High System Reliability
- Optimal Price Performance
- Reduced Cooling Requirements
- Increased System Power Density
- Zero Reverse Recovery Current
- Easy to Parallel without Thermal Runaway
- Improved System Efficiency

#### **Applications**

- EV Fast Chargers
- Solar Inverters
- Wind Energy Converters
- Train Auxiliary Power Supplies
- High Frequency Rectifiers
- Switched Mode Power Supplies
- Motor Drives
- Pulsed Power

Parameter	Symbol	Conditions	Values	Unit	Note
Repetitive Peak Reverse Voltage (Per Leg)	$V_{RRM}$		1700	V	
Continuous Forward Current (Per Leg / Per Device)	l <sub>F</sub>	T <sub>C</sub> = 75°C, D = 1 107 / 214			
		$T_C = 100^{\circ}C, D = 1$	91 / 182	Α	Fig. 4
		$T_C = 148^{\circ}C, D = 1$	50 / 100		
Non-Repetitive Peak Forward Surge Current, Half Sine	I <sub>F,SM</sub>	$T_C$ = 25°C, $t_P$ = 10 ms	540	А	
Wave (Per Leg)		$T_C = 150^{\circ}C$ , $t_P = 10 \text{ ms}$	432		
Repetitive Peak Forward Surge Current, Half Sine Wave	les	$T_C$ = 25°C, $t_P$ = 10 ms	324	Α	
(Per Leg)	I <sub>F,RM</sub>	$T_C = 150^{\circ}C$ , $t_P = 10 \text{ ms}$	227	A	
Non-Repetitive Peak Forward Surge Current (Per Leg)	I <sub>F,MAX</sub>	$T_C = 25^{\circ}C$ , $t_P = 10 \mu s$	2700	Α	
i²t Value (Per Leg)	∫i²dt	$T_C$ = 25°C, $t_P$ = 10 ms	1458	A <sup>2</sup> s	
Non-Repetitive Avalanche Energy (Per Leg)	E <sub>AS</sub>	$L = 1.0 \text{ mH}, I_{AS} = 50 \text{ A}$	1301	mJ	
Diode Ruggedness (Per Leg)	dV/dt	V <sub>R</sub> = 0 ~ 1360 V	200	V/ns	
Power Dissipation (Per Leg / Per Device)	P <sub>TOT</sub>	T <sub>C</sub> = 25°C	590 / 1180	W	Fig. 3
Operating and Storage Temperature	T <sub>j</sub> , T <sub>stg</sub>		-55 to 175	°C	

<sup>\*</sup> Per Device



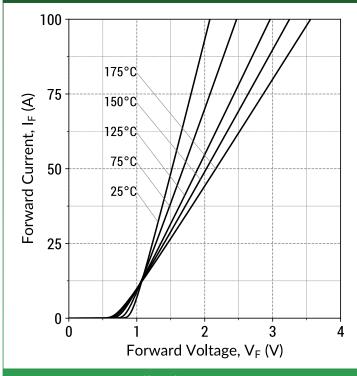


Electrical Characteristics (Per Leg)								
Parameter	Symbol	Conditions		Values			Unit	Note
	Symbol			Min.	Typ.	Max.	Oilit	Note
Diode Forward Voltage	$V_{F}$	$I_F = 50 \text{ A, } T_j = 25^{\circ}\text{C}$			1.5	1.8	V	Fig. 1
	VF	I <sub>F</sub> = 50 A, T <sub>j</sub> = 175°C			2.1			
Reverse Current	I-	V <sub>R</sub> = 1700 V, T <sub>j</sub> = 25°C			2	10	μΑ	Fig. 2
	I <sub>R</sub>	$V_R = 1700 \text{ V, T}_j = 175^{\circ}\text{C}$			42			
Total Capacitive Charge	Qc		V <sub>R</sub> = 600 V		368		nC	Fig. 7
	QС	_ l <sub>F</sub> ≤ l <sub>F,MAX</sub> dl <sub>F</sub> /dt = 200 A/μs	$V_R = 1200 \text{ V}$		538			
Switching Time	+-		V <sub>R</sub> = 600 V		< 10		no	
	ts		$V_R = 1200 \text{ V}$		<b>\ 10</b>		ns	
Total Capacitance	С	$V_R = 1 \text{ V, } f = 1 \text{ MHz}$ $V_R = 1200 \text{ V, } f = 1 \text{ MHz}$			4701		nЕ	Fig. 6
					259		pF 	

Thermal/Package Characteristics							
Parameter	Symbol	Conditions	Values			- Unit	Note
			Min.	Typ.	Max.	Ullit	Note
Thermal Resistance, Junction - Case (Per Leg)	R <sub>thJC</sub>			0.25		°C/W	Fig. 9
Weight	W <sub>T</sub>			28.0		g	
Mounting Torque	T <sub>M</sub>	Screws to Heatsink			1.5	Nm	
Terminal Connection Torque	T <sub>C</sub>	M4 Screws			1.3	Nm	
Isolation Voltage(RMS)	V <sub>ISO</sub>	t = 1s (50/60 Hz)	3000				
		t = 60s (50/60 Hz)		2500		V	
Creepage Distance on Surface	dctt	Terminal to Terminal		10.5		no no	
	$d_{Ctb}$	Terminal to Backside		8.5		mm	
Striking Distance Through Air	dstt	Terminal to Terminal		3.2		na na	
	d <sub>Stb</sub>	Terminal to Backside		6.8		mm	

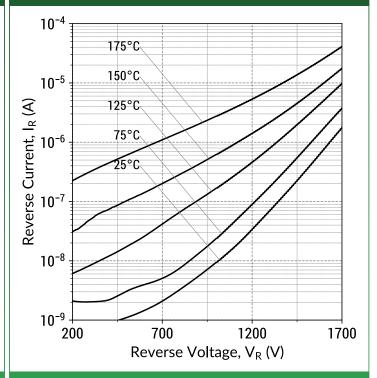






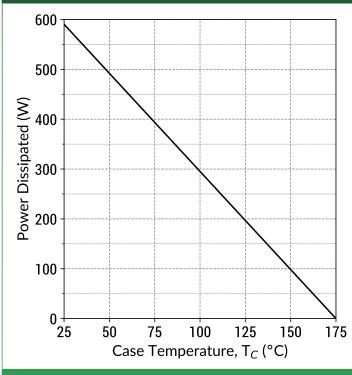
 $I_F = f(V_F, T_j); t_P = 250 \ \mu s$ 

Figure 2: Typical Reverse Characteristics (Per Leg)



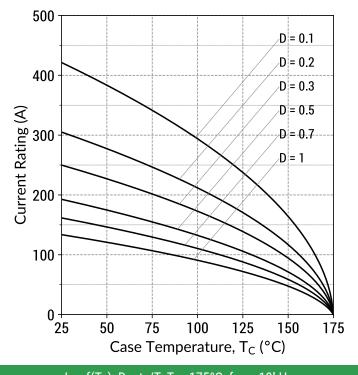
 $I_R = f(V_R, T_j)$ 

Figure 3: Power Derating Curves (Per Leg)



 $P_{TOT} = f(T_C); T_j = 175^{\circ}C$ 

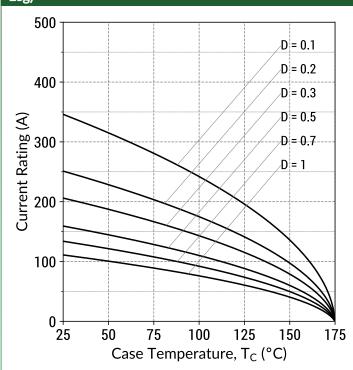
Figure 4: Current Derating Curves (Typical V<sub>F</sub>) (Per Leg)



 $I_F = f(T_C); D = t_P/T; T_j \le 175^{\circ}C; f_{SW} > 10kHz$ 

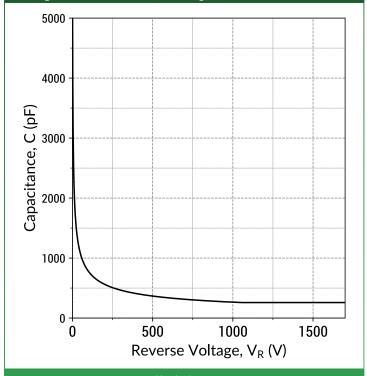


Figure 5: Current Derating Curves (Maximum  $V_F$ ) (Per Leg)



 $I_F = f(T_C); D = t_P/T; T_j \le 175^{\circ}C; f_{SW} > 10kHz$ 

Figure 6: Typical Junction Capacitance vs Reverse Voltage Characteristics (Per Leg)



 $C = f(V_R)$ ; f = 1MHz

Figure 7: Typical Capacitive Charge vs Reverse Voltage Characteristics (Per Leg)

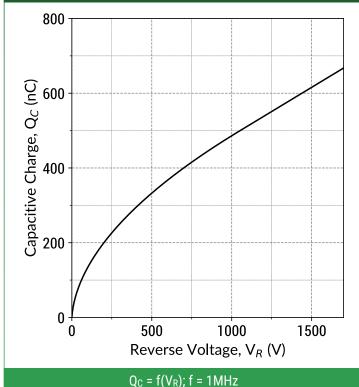


Figure 8: Typical Capacitive Energy vs Reverse Voltage Characteristics (Per Leg)

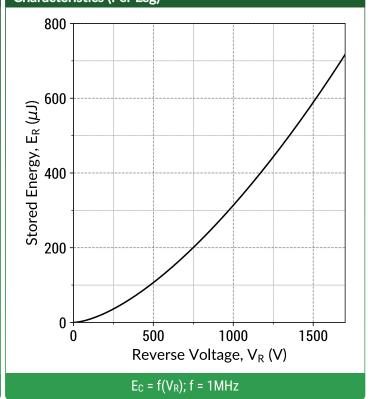
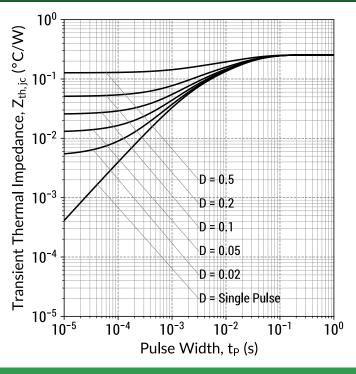


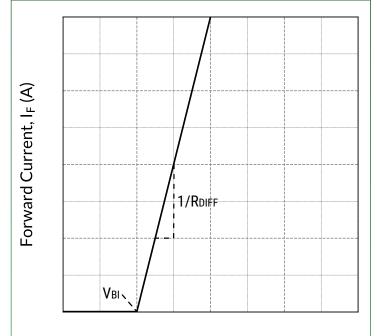


Figure 9: Transient Thermal Impedance (Per Leg)



 $Z_{th,jc} = f(t_P,D); D = t_P/T$ 

Figure 10: Forward Curve Model (Per Leg)



Forward Voltage,  $V_F$  (V)

 $I_F = f(V_F, T_j)$ 

## Forward Curve Model Equation:

 $I_F = (V_F - V_{BI})/R_{DIFF}(A)$ 

#### Built-In Voltage (V<sub>BI</sub>):

$$V_{BI}(T_j) = m \times T_j + n (V)$$
  
 $m = -0.00128 (V/^{\circ}C)$   
 $n = 0.99 (V)$ 

#### Differential Resistance (RDIFF):

$$R_{DIFF}(T_j) = a \times T_j^2 + b \times T_j + c (\Omega)$$
  
 $a = 2.03e-07 (\Omega/^{\circ}C^2)$   
 $b = 7.11e-05 (\Omega/^{\circ}C)$   
 $c = 0.0093 (\Omega)$ 

#### **Forward Power Loss Equation:**

 $P_{LOSS} = V_{BI}(T_j) \times I_{AVG} + R_{DIFF}(T_j) \times I_{RMS}^2$ 



# Package Dimensions SOT-227 Package Outline 0.472 (11.9) 0.480 (12.19) 1.240 (31.5) 0.372 (9.45) 1.255 (31.88) 0.378 (9.60) 0.310 (7.87) 0.322 (8.18) 0.108 (2.74) 0.124 (3.15) Ø <u>0.163 (4.14)</u> 0.169 (4.29) R 3.97 1.049 (26.6) 1.059 (26.90) 0.163 (4.14) 0.990 (25.1) 1.000 (25.40) 0.495 (12.5) 0.506 (12.85) 0.172 (4.37) 0.164 (4.16) 0.174(4.42) 0.080 (2.03) 0.234 (5.94) 0.084 (2.13) 0.165 (4.19) 0.169 (4.29) 0.030 (0.76) 0.033 (0.84) 0.588 (14.9) 0.594 (15.09) 1.186 (30.1) 1.192 (30.28) 1.494 (37.9) 1.504 (38.20) Package View **Isolated Base**

#### **NOTE**

- 1. CONTROLLED DEIMENSION IS INCH. DIMENSION IN BRACKET IS MILLIMETER.
- 2. DIMENSIONS DO NOT INCLUDE END FLASH, MOLD FLASH, MATERIAL PROTRUSIONS.





## **RoHS Compliance**

The levels of RoHS restricted materials in this product are below the maximum concentration values (also referred to as the threshold limits) permitted for such substances, or are used in an exempted application, in accordance with EU Directive 2011/65/EC (RoHS 2), as adopted by EU member states on January 2, 2013 and amended on March 31, 2015 by EU Directive 2015/863. RoHS Declarations for this product can be obtained from your GeneSiC representative.

#### **REACH Compliance**

REACH substances of high concern (SVHCs) information is available for this product. Since the European Chemical Agency (ECHA) has published notice of their intent to frequently revise the SVHC listing for the foreseeable future, please contact a GeneSiC representative to insure you get the most up-to-date REACH SVHC Declaration. REACH banned substance information (REACH Article 67) is also available upon request.

This product has not been designed or tested for use in, and is not intended for use in, applications implanted into the human body nor in applications in which failure of the product could lead to death, personal injury or property damage, including but not limited to equipment used in the operation of nuclear facilities, life-support machines, cardiac defibrillators or similar emergency medical equipment, aircraft navigation or communication or control systems, or air traffic control systems.

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#### **Related Links**

SPICE Models: https://www.genesicsemi.com/sic-schottky-mps/GB2X50MPS17-227/GB2X50MPS17-227\_SPICE.zip
 PLECS Models: https://www.genesicsemi.com/sic-schottky-mps/GB2X50MPS17-227/GB2X50MPS17-227\_PLECS.zip
 CAD Models: https://www.genesicsemi.com/sic-schottky-mps/GB2X50MPS17-227/GB2X50MPS17-227\_3D.zip

Evaluation Boards: https://www.genesicsemi.com/technical-support

Reliability: https://www.genesicsemi.com/reliability
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